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Light outcoupling strategies in oriented perovskite light-emitting-diodes: recent trends, opportunities, and challenges toward innovation

This work highlights the recent progress on the light outcoupling in perovskite LEDs to achieve high external quantum efficiency.

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Light outcoupling strategies in oriented perovskite light-emitting-diodes: recent trends, opportunities, and challenges toward innovation

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Metal halide perovskites (MHPs) exhibit outstanding photophysical properties, such as high photoluminescence quantum yield (PLQY), high exciton binding energy, narrow emission spectrum, tailorable bandgap, and facile solution-processibility. MHPs have opened a scientific revitalization in the light-emitting diode (LED) technology. Tremendous research efforts have been carried out, such as balancing electron–hole injection, modulation of stoichiometric compositions, ligand engineering, and minimal non-radiative recombination that boosted the internal quantum efficiency near unity. However, the lower external quantum efficiency and operational stability of perovskite LEDs (PeLEDs) than organic LEDs make them limited to display and lighting applications. One of the main reasons is the trapped photons inside the devices, which reduces light outcoupling. This review includes a detailed analysis of existing challenges in managing light outcoupling of PeLEDs and discusses various strategies adopted for these challenges. Control of dipole orientations, refractive index matching, oriented quasi-two-dimensional structures, and thickness optimization are existing methodologies to address the improved light outcoupling in PeLEDs. We discuss a detailed prospect for high-performance PeLEDs for practical applications.

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1. Introduction

Over the past few decades, tremendous efforts have been devoted to developing new semiconductors with outstanding electronic and optical properties. With the development of materials science combined with innovative device fabrication methodologies, numerous high-performance optoelectronic devices have been developed, including photodetectors,^{1–6} photovoltaic cells,^{7–9} light-emitting diodes (LEDs),^{10–12} and transistors.^{13–16} The successful realizations of optimized morphologies, including nanostructures, single-crystal wafers, and thin films, have allowed countless optoelectronic devices to meet the end-users prospects.^{17–20} The low-dimensional semiconducting materials, such as 0D quantum dots, 1D nanowires/nanorods, 2D quantum wells, and 3D hierarchical structures, possess tunable optical and electrical properties. Furthermore, they allow for diverse light-matter interactions as well as high aspect ratios stemming from their unique surface morphology, contrary to bulk counterparts. Notably, the crystallographic orientation among the low-dimensional semiconducting materials is essential as a building block for various optoelectronic devices.

The well-defined morphology of oriented nanostructures has the ability for directional charge separation or transfer, and homo-/hetero-junction formation with other semiconductors.^{21,22} Thus, these properties promote the performance of oriented nanostructures and serve as an effective avenue for the fundamental photophysical exploration of numerous materials.

In recent years, the development of well-defined size, shape, and controlled surface morphologies of oriented nanostructures has been successfully realized, and their potential application in high-performance optoelectronic devices has been demonstrated. To this end, metal halide perovskites (MHPs) have emerged as exciting semiconducting materials for next-generation display and lighting applications due to their excellent photophysical properties, tailorable bandgap, and solution-processibility. The general chemical formula of a 3D perovskite structure is ABX_3 , where A is a monovalent cation (MA, $(CH_3NH_3)^+$, FA, $(HCNH_2)_2^+$, Cs^+), B is a divalent cation, and X is a halide anion (Cl^- , Br^- , I^-). In ABX_3 structures, the BX_6 structure is formed so that one divalent metal cation is connected to six halide anions, as shown in the 3D structure of MHP (Fig. 1a). Unlike the bulk 3D perovskite, the reduced dimension is low-dimensional, such as quantum dots, 1D nanowires/nanorods, and 2D nanosheets/nanoplatelets (Fig. 1b). These perovskites possess distinctive advantages of quantum-confinement effects and shape diversity.

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Fig. 1 (a and b) Simulated structures and schematic illustration of material-level, structure-level 3D perovskites, and their low-dimensional counterparts, respectively. Reproduced with permission.⁶⁴ Copyright 2020, Wiley-VCH.

The general chemical formula of mixed quasi-two-dimensional Ruddlesden–Popper (RP) is $L_2A_{n-1}Pb_nX_{3n+1}$, where L (phenyl-ethyl ammonium (PEA), butylammonium (BA)) is a large aromatic or aliphatic alkyl ammonium cation, A is an organic cation, B is a divalent metal cation, X is a halide anion, and n is the number of inorganic layers.^{23,24} The replacement of bulky organic cations with small organic cations (PEA, BA) resulted in the formation of a quasi-two-dimensional perovskite structure. These quasi-2D layered structures are oriented organic and inorganic layers, and octahedral $[BX_6]^{4-}$ inorganic layers are sandwiched by the two layers of PEA, BA counter cations. Thus, naturally occurring quantum wells and multi-bandgap structures that tightly confined excitons within organic layers enhance the photoluminescence quantum yield (PLQY) by suppressing the non-radiative recombination (Fig. 1a and b). The RP quasi-two-dimension perovskite energy level and bandgap can be determined from the dimensionality. Due to quantum confinement effects, the bandgap gradually increases as n number of inorganic layers decreases from ∞ (3D) to 1 (2D). The RP-phased MHPs of $n = 1$ or 2 are highly efficient for eliminating non-radiative recombination rates, owing to the enhanced electron–hole pair confinement in these phases.

The past five years have witnessed the rapid advancement of MHP by optimizing their optoelectrical properties, including high PLQY, emission color purity, tailorable bandgap, and high charge carrier mobilities to meet the internal quantum efficiency close to unity.^{5,25–30} The utilization of MHP in optoelectronic devices could eliminate the drawback associated with conventional semiconductors (*e.g.*, organic or

Cd/Zn-chalcogenides QDs). For instance, in 2009, the photovoltaic function of MHP with a power conversion efficiency of 3.8% was reported. Soon after this report, it was observed that high PLQY and suppressed defect formation in MHP should be an ideal candidate for luminance devices.⁷ These properties and low-temperature solution-processibility have propelled the MHP for modern lighting and display technologies.

In 2014, Richard H. Friend's group introduced room-temperature perovskite light-emitting diodes (PeLEDs) with a luminance efficiency of 364 cd m^{-2} and external quantum efficiency (EQE) below 0.1%.³¹ This work set a new standard for triggering the fast development of PeLEDs in display applications as they have a distinct advantage over the current main display source, organic LEDs, in terms of the high color purity covering the REC.2020 standard with narrow full-width at half-maximum (FWHM) emission spectra.

Since the pioneering work, immense efforts have been devoted to further improving the performance of PeLEDs, making the EQE close to the value of organic LEDs. Researchers have emulated past breakthroughs to explore numerous oriented perovskite nanostructures to enhance the intrinsic emission characteristics of perovskites. For example, Lee *et al.* studied the excess of metallic lead (Pb) in perovskite to eliminate the non-radiative recombination rates.³² An optimized amount of Pb in perovskite led to an optimized morphology, such as well-packed nanograins with uniform coverage from scattering micro-sized cuboids. This strategy induced enhanced light outcoupling, leading to a 20 000-fold efficiency increment in PeLEDs compared with control devices. Xiong *et al.* reported

the colloidal synthesis of MAPbBr₃ nanoparticles with a diameter of less than 10 nm.³³ These colloidal nanoparticles possessed a high PLQY of over 90%, including large exciton binding energy, which enabled PeLEDs efficiency of 3.8%. Wang *et al.* reported on multiple quantum wells perovskite with energy-funneling to reduce non-radiative recombination rates associated with defects and leakage current.³⁴ The multiple quantum wells perovskites boosted electroluminescence due to the confinement in lower energy gap quantum wells by higher energy gaps quantum wells, resulting in an improved EQE of over 11%. The EQE of 14.36% was reported based on optimized quasi-two-dimensional perovskites through composition, phase engineering, and surface engineering.³⁵ The EQE of over 20% was obtained with quasi-core shell techniques that effectively passivated non-radiative recombination losses, boosting the PLQY.³⁶ Additionally, an EQE of 28.9% was reported using a simple *in situ* reaction of benzyl phosphonic acid additive with three-dimensional (3D) polycrystalline perovskite films.³⁷ Fig. 2 shows the yearly progress of green, infrared, sky-blue, and blue PeLEDs, with the highest value of green PeLEDs now at more than 28.9% (average = 25.2 ± 1.6%), approaching the theoretical limit of isotopically orientated perovskites emitters.^{37–63}

Although PeLEDs have shown significant progress in enhancing the EQE, their EQE value still lags behind that of OLEDs, which is currently close to 40%. The difference in EQE between PeLEDs and OLEDs stems from the disparity in the outcoupling efficiency assuming that IQE is nearly unity. For further enhancement in EQEs of PeLEDs, it is essential to manage light outcoupling. When considering the device structure of PeLEDs compared to organic LEDs, the difference is only the emitting layer since the other layers are almost similar in the two cases. However, despite the encouraging efforts that have been made for balancing electron-hole injection, modulation of stoichiometric compositions, ligand engineering, and minimal non-radiative recombination, the outcoupling management of PeLEDs has scarcely been explored compared to that of organic LEDs. Therefore, this review focuses on recent advancements in

oriented perovskite nanostructures of their application in PeLEDs to improve the outcoupling efficiency. Notably, this review is targeted at giving a complete overview of the oriented growth of perovskites along the specific direction to enhance the light extraction efficiency of PeLEDs. The high horizontal dipole ratios of the anisotropic perovskite emitter, the divergence of refractive indices, the photon-recycling process, and film thickness for outcoupling efficiency improvement have been discussed in detail.

2. Light-outcoupling in perovskite light-emitting diodes

The EQE (η_{EQE}) of PeLEDs is a function of the internal quantum efficiency (η_{IQE}) and outcoupling efficiency (η_{out}), and can be expressed with eqn (1):

$$\eta_{\text{EQE}} = \eta_{\text{IQE}} \times \eta_{\text{out}} = f_{\text{balance}} \times f_{\text{e-h}} \times \eta_{\text{radiative}} \times \eta_{\text{out}} \quad (1)$$

where f_{balance} is the probability of balanced charge injection (when the numbers of electrons and holes injected are equal, this factor is equal to 1), $f_{\text{e-h}}$ is the probability of forming a correlated electron-hole pair or exciton from each pair of injected carriers, and $\eta_{\text{radiative}}$ is the probability of radiative recombination for each electron-hole pair.⁶⁵ The η_{IQE} of PeLEDs can now approach near unity, enabled by the abundantly proposed strategies.^{34,66–73} However, the external efficiency in standard PeLEDs remains severely limited due to the poor η_{out} caused by numerous internal optical losses.

The η_{out} of PeLEDs typically depends on parameters such as the angle of emissive transition dipole moments (TDMs) in-plane or out-of-plane with the substrate surface, film thickness, photon-recycling process, and refractive indices of the consisting layer. In PeLEDs, the outcoupling efficiency losses are ascribed to a series of optical modes, such as waveguide mode, surface plasmon polaritons, substrate mode, and intrinsic absorption mode.⁷⁴ The waveguide mode is mainly owing to the discrepancy between the refractive index of the vertically stacked consisting layers in the device that confined more than 20% of the generated photons.⁷⁵ Additionally, the surface plasmon polaritons mode (20–30%), absorption mode (<10%), and substrate mode (10–30%) dissipate the different portions of generated light within the device.^{76,77} Namely, the refractive index (n) gap between the active layers and the ambient medium severely hampered the η_{out} . According to classic ray optics, the n of the randomly oriented TDM-based active layers and η_{out} are related by $\eta_{\text{out}} = 1/2n^2$. For perovskite emissive layers typically having n of 2.0–2.6, the η_{out} is limited to 15%, which severely reduces the η_{EQE} of PeLEDs.^{78,79}

Film thickness is another influencing factor to η_{out} . The optimized film thickness of EML and Indium tin oxide (ITO) layers significantly impacts the density of trapped light within the waveguide and substrate mode. The theoretical results reveal that 40% of generated light can be outcoupled with the optimized thickness of ITO and EML layers.^{80,81} Additionally, the photon recycling process is an important parameter to

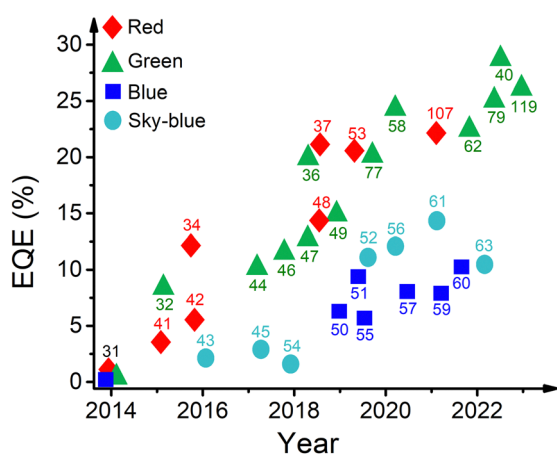


Fig. 2 The recent progress of red (diamonds), green (triangles), blue (squares), and sky-blue (circles) PeLEDs. The numbers correspond to their respective reference numbers.

understand the outcoupling efficiency of PeLEDs beyond the predicted value of classical ray-optics theory.

For the details, we will discuss the extraction of internally trapped electroluminescence, with the oriented growth of perovskites, template-assisted, pattern-nanophononics-assisted growth, oriented TDMs, and refractive indices matching. Film thickness optimization and the photon recycling process's role in enhancing outcoupling are also presented in this review. This review comprises numerous research efforts developed to extract generated photons from the device.

2.1. Refractive indices matching

Owing to the complex photonic process in perovskites EML, the efficiency gap between the state-of-art organic LEDs and PeLEDs is quite high. The predominant reason is the high index of the perovskite emissive layer ($n > 2.2$) relative to the ambient medium ($n = 1$), leading to the induction of enormous optical losses, unlike OLEDs having $n \approx 1.7$ – 1.8 for transporting layers and EML. The refractive index mismatching in the perovskite multilayered structure gives rise to modifying the outcoupling angle. If the angle is very small, the generated photons in the EML are hardly extracted. Thus, reducing the EML index increases the outcoupling angle and thus has the potential to increase the outcoupling efficiency. However,

the enhanced outcoupling does not always make the brightness boost. For the brightness, we only count the number of photons emitted close to a normal angle to the surface of the substrate (in-between 0° and less than 3° angles). However, for outcoupling, one counts the photon flux from all angles. Thus, after the refractive index modification, photons at a higher angle likely contribute to enhancing outcoupling, rather than the ones at the normal 0° angle, which are already extracted out even in the devices without the modification of n . To simultaneously enhance the outcoupling and brightness, other strategies should be combined to change the path of the photons at a high angle when extracted. Here, we will focus on the outcoupling enhancement *via* refractive index modification.

As shown in the previous literature, the effective management of refractive indices of consisting layers in PeLEDs is one of the crucial determinants to enhancing the outcoupling efficiency.^{78,79} The η_{out} corresponds to the fraction of light escaping from the PeLED stack, deducting from the interfacial total-internal-reflection and Purcell-effect losses.⁸² The C.-J. Shih group reported on the $\text{FA}_{0.5}\text{MA}_{0.5}\text{PbBr}_3$ nanocrystals capped with alkylamine amphiphiles with different hydrophobic tail groups to control the ligand hydrophobicity.⁸³ The alkylamine amphiphiles capped $\text{FA}_{0.5}\text{MA}_{0.5}\text{PbBr}_3$ nanocrystals possess effective n values of 1.64–1.75 (Fig. 3a), corresponding

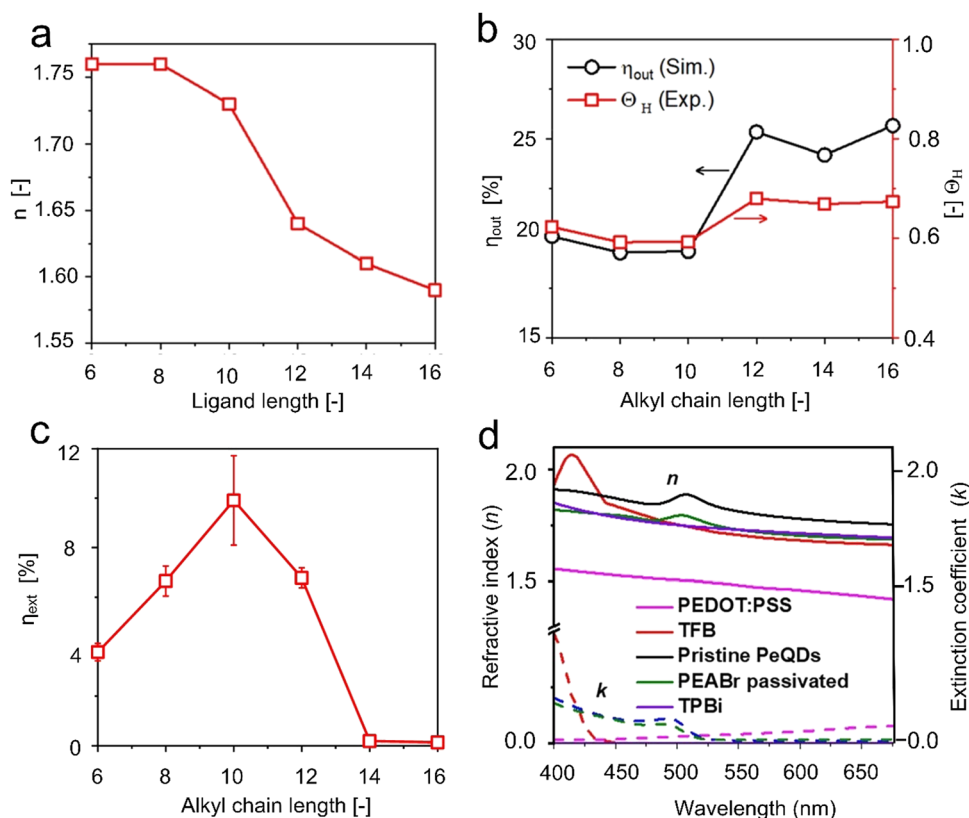


Fig. 3 (a) The n profile of $\text{FA}_{0.5}\text{MA}_{0.5}\text{PbBr}_3$ perovskite nanocrystals capped with alkylamine ligands varying the alkyl chain length. (b) Extracted probability of horizontal transition dipole moments (Θ_{H}) and calculated light outcoupling efficiency, η_{out} , as a function of alkyl chain length, and (c) η_{ext} distribution as a function of the alkyl chain.⁸³ Copyright 2019, American Chemical Society. (d) Refractive indices (n) and extinction coefficients (k) of the PEDOT:PSS, TFB, pristine CsPbBr_3 , phenylethyl ammonium-passivated CsPbBr_3 , and TPBi in PeLED as a function of wavelength. Reproduced with permission.⁷⁵ Copyright 2021, Elsevier.

to a maximum η_{out} of 26%, the maximum luminance of 3322 cd m^{-2} and η_{ext} of 9.01% based on the $\text{FA}_{0.5}\text{MA}_{0.5}\text{PbBr}_3$ nanocrystals PeLED (Fig. 3b and c). Hassan *et al.* synthesized $\text{MAPb}(\text{I}_x\text{Br}_{1-x})_3$ nanocrystals employing a modified ligand-assisted re-precipitation method.⁸⁴ The $n \sim 1.82$ (620 nm), η_{out} (32.2%), and η_{ext} of 20% were estimated from the $\text{MAPb}(\text{I}_x\text{Br}_{1-x})_3$ nanocrystals-LEDs.

Additionally, He *et al.* reported that the effectiveness of the organic cation ligand exchange is an attractive approach to lower the large contrast n of the transporting layer and perovskite EML.⁷⁵ The pristine CsPbBr_3 and passivated films exhibit n values of 1.91 and 1.82 at 520 nm, respectively. The lower n value in the passivated film indicates the coupling associated with the ligand exchange. Consequently, an efficiency enhancement was reported from 1.0% to 6.85% and luminance from 1300 cd m^{-2} to 13000 cd m^{-2} for the control and passivated CsPbBr_3 PeLEDs, respectively. The improved performance of phenylethyl ammonium- CsPbBr_3 passivated PeLEDs was attributed to enhanced light-outcoupling efficiency owing to the reduced n value (Fig. 3d). Subsequently, the n of the perovskite emissive layer can be adjusted by using a pre-deposited thin layer of poly(2-hydroxyethyl methacrylate), pHEMA.⁷⁶ The refractive index of pHEMA is around 1.9 (calculated at the peak of its steady-state luminescence), and halide perovskite is $n \sim 2.7$, and this discrepancy of n value significantly trapped the generated light of more than 70%. The pre-deposited

thin layer of pHEMA before the ensemble of the perovskite film helped to suit the n (~ 2.1) values. It extended the escape cone of photon emission from the bulk heterojunction perovskite emissive layer to an angle of 32° , leading to an efficiency of up to 20.1%, with operation stability of $T_{50} = 46 \text{ h}$ in the air at peak external quantum efficiency. The theoretical analysis also revealed that an outcoupling enhancement factor of up to 25% could be obtained from the modified EML.

In addition, several nanophotonics/nanopatterns strategies were implemented to enhance the outcoupling efficiency by overcoming the refractive index mismatch. For example, the utilization of rational nanostructures assists in adapting the refractive index matching within devices. Zhang *et al.* introduced 3D anodic alumina membranes-based nanophotonic substrate.⁸⁵ By properly controlling the refractive index, the substrate with a nanowire array optical antenna layer acts as a nano-dome array light coupler (Fig. 4a). Therefore, the generated light can easily propagate through the anodic alumina membrane (TiO_2 nanowires) layer in the vertical direction with reduced light trapping inside the device. For the optimization of the outcoupling, they claimed that the barrier layer nanodomains and TiO_2 nanowires array embedded in anodic alumina membrane nanophotonic with pitch size of 1000 nm is more beneficial than a planner and without TiO_2 nanowires nanodomains anodic alumina membrane devices. It originates from the core index matching between the TiO_2 ($n = 2.7$) and

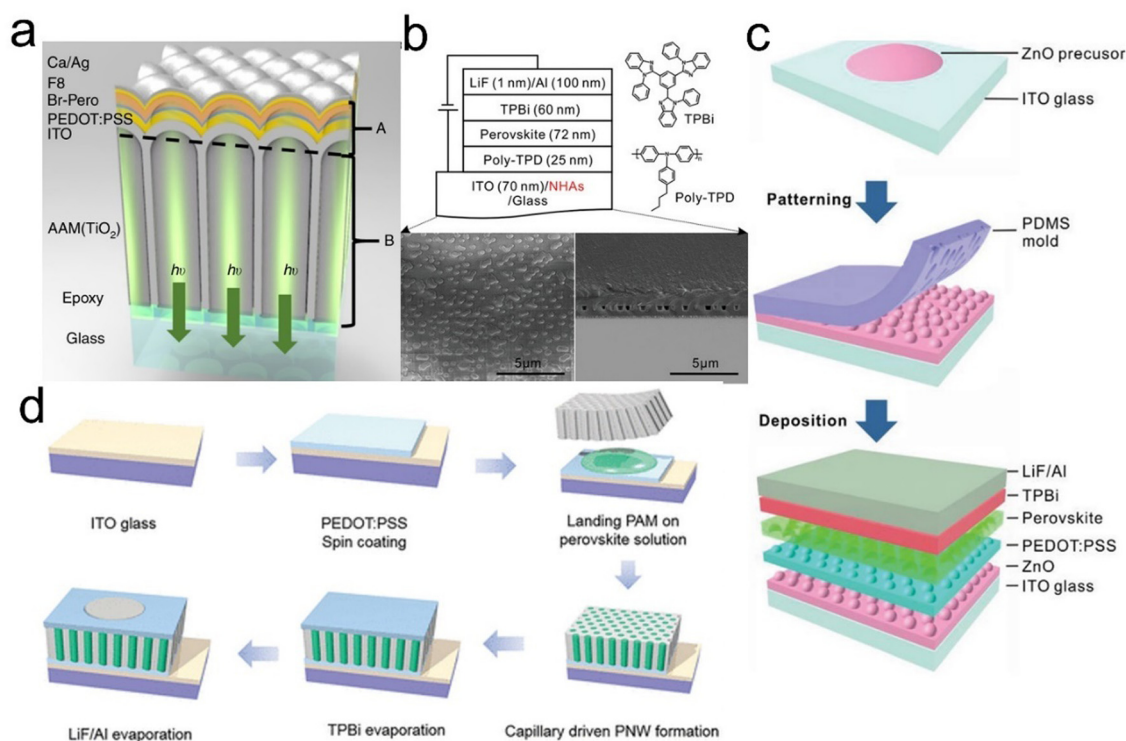


Fig. 4 (a) Schematic illustration of the vertical TiO_2 nanowires-based LED device. Cathode/F8/perovskite/PEDOT:PSS/ITO/anodic alumina membrane filled with TiO_2 nanowires array. Reproduced with permission.⁸⁵ Copyright 2019, Nature Publishing Group. (b) Device structures of PeLEDs with and without nanohole arrays. Reproduced with permission.⁸⁶ Copyright 2019, Wiley-VCH. (c) Graphic representation of the fabrication process of PeLED with the imprinted nanostructures. Reproduced with permission.⁸⁷ Copyright 2019, Wiley-VCH. (d) The fabrication process of the nanowires PeLEDs. Reproduced with permission.⁸⁸ Copyright 2020, American Chemical Society.

perovskites ($n = 2.6$) to form a waveguide to support guided modes coupled from perovskite layers. This nanophotonic structure with nano-domes light couplers and nanowire optical antennas leads to a light extraction efficiency of over 73%, an external efficiency of more than 17%, and a luminance of $48\,668\text{ cd m}^{-2}$ at 4 V. Despite the high light extraction efficiency (73%) in this configuration, the low internal quantum efficiency of the emitter makes EQE low (17%). It can be inferred that the EQE of PeLEDs can overcome 30% if we combine a high IQE emitter with this technology.

Jeon *et al.* have explored the potential of a nanophotonic structure composed of a randomly distributed nanohole array with a high-index contrast that facilitates light extraction efficiency.⁸⁶ The randomly distributed nanohole array voids with a 300 nm depth in the SiN layer are propitious for light extraction due to the high n contrast between SiN and the void (Fig. 4b). The finite-difference time-domain simulation results demonstrate that without a randomly distributed nanohole array nanophotonic structure, 87% of the generated light is trapped within the device owing to the divergence of refractive indices between the perovskite emitter and glass substrate. However, randomly distributed nanohole array-embedded PeLEDs provide additional opportunities for light outcoupling enhancement, so a 1.46-times higher efficiency was obtained from this nanohole array structure. More importantly, the near-infrared perovskite LEDs reached a brightness of $16.5\text{ W sr}^{-1}\text{ m}^{-2}$ without the randomly distributed nanohole array nanophotonic structure and $23.7\text{ W sr}^{-1}\text{ m}^{-2}$ with the randomly distributed nanohole array nanophotonic structure. Thus, improved outcoupling in PeLEDs was acquired by employing a nanohole array composed of SiN with embedded voids.

These approaches have enabled the significant reduction of the density of trapped light within the PeLEDs, leading to substantial outcoupling improvement. Furthermore, Shen *et al.* explored an economical method to effectively eliminate the optical losses associated with the waveguide mode by embedding imprinted bioinspired moth-eye nanostructures at the perovskites anode interface (Fig. 4c).⁸⁷ The trapping of photons within the waveguide mode had been significantly lessened with the moth-eye nanostructure technique. Subsequently, moth-eye nanostructure-based PeLEDs retained 1.5-times higher performance than flat devices owing to the improvement associated with the efficient outcoupling of the waveguided light.

The directional growth of perovskite nanostructures allows us to achieve enhanced light outcoupling in PeLEDs by activating the radiative and directional emission with better stability provided by the nanostructures-patterned template with the high-index grading of perovskite. Thus, the directional growth of the emissive layer offers an additional benefit of improving the photon management, high-index matching, and superior stability, contrary to planner devices. For example, the growth of the methylammonium bromide (MABr)-modified CsPbBr₃ nanophotonic wire LEDs in a porous alumina membrane has been explored with the capillary-effect-assisted solution method (Fig. 4d).⁸⁸ The efficiency and stability of template-assisted nanophotonic wire-based PeLEDs were

increased to 1.45 and 3.89 times compared to the planner device, respectively, owing to the 4 to 5 times (44–51%) increase in the light extraction coefficient of the nanophotonic wire PeLEDs, compared with a light extraction coefficient of the planner device (10%). Additionally, the nanophotonic wire-based PeLEDs can give a luminance of $12\,016\text{ cd m}^{-2}$ at 5.5 V, and the planner device only gives $10\,953\text{ cd m}^{-2}$ at the same voltage. Thus, the maximum luminance was enhanced by 9.7%, owing to the better light extraction coefficient of the nanophotonic wire.

2.2. Control the orientation of perovskite thin film

The directional growth of nanostructured materials would be advantageous for LED technology, owing to the control of light outcoupling by eliminating the drawback associated with optical trapping within the thin film layers of ITO, a hole-transporting layer, and EML. Subsequently, enormous research efforts have been reported to discover the optoelectronic properties and stability of directional nanostructural materials, including pattern 1D nanophotonic, submicrometer-scale structures, nanorods, nanowires, and quasi-2D perovskites-based LEDs.^{20,89–93} Among them, strong dielectric- and quantum-confinement effects owing to the large exciton binding energy with quantum well nature and high PLQY of 2D perovskites have emerged as sensational contenders for LED technologies. Even though the internal efficiency of 0D and 3D PeLEDs is equal to unity, an EQE beyond 20% is hardly achievable due to limited outcoupling. Conversely, the EQE of 2D PeLEDs can achieve over 25%, enabled by the anisotropic emitter outstripping the intrinsic light outcoupling limit in PeLEDs.⁷⁹

To realize anisotropic light emission, it is crucial to orient the TDM, a vector quantity associated with the direction of the electronic oscillation between the ground and emissive elements of emitting materials. In general, TDMs that are horizontally oriented with respect to the substrate are favored for light outcoupling, while vertically oriented TDMs largely contribute to energy loss in vertically stacked architectures.⁹⁴ In this way, horizontally oriented TDMs with the crystal facing parallel to the substrate surface induce more light extraction from the substrate by reducing the guided and substrate modes, which can compensate for the refractive mismatching issue.

The angular dependence PL spectra and back focal plane imaging were investigated to quantify the orientation of TDMs. The experimental setup for obtaining the angle-dependent PL consists of a mounted glass slide with a thin layer of nanoplate film onto a half-cylindrical prism (Fig. 5a). The intensity of the emitted photons is measured per an angle after exciting the film with the appropriate power and wavelength of the laser source. The emitting light from this experiment is used in conjunction with the 1D microcavity model.⁹⁵ This model effectively estimates the anisotropy of the emitting materials and provides information on the alignment constant (ζ).⁹⁶ The value of the alignment constant ($\zeta = 0, 1$) is bound between zero and one for horizontally and vertically aligned TDMs with the ensemble film, respectively. The alignment constant,

the refractive index, and the angle of the emissive TDM to the film substrate is given by eqn (2):

$$\varphi = \arcsin\left(\sqrt{\frac{n^4\zeta}{1+n^4\zeta-\zeta}}\right) \quad (2)$$

where ζ is the alignment constant, n refractive index, and φ is the angle of TDMs. Although the rigorous in-plane orientation of TDMs ($\zeta = 0$) in 2D ensemble films remains elusive, a value of alignment constant ($\zeta = 0.019$) corresponds to an angle of 29° between the surface ensemble film and the transition dipole moment vector.⁹⁷ The value of the alignment constant determines the angle of the TDM vector (Fig. 5b).⁹⁶ Furthermore, the resulting TDM angle for a given value of ζ depends on the sample's refractive index. The purple line depicts the expected behavior for the perovskite films (Fig. 5c). The power factors of outcoupled, substrate, waveguide, surface plasmons, and non-radiative loss optical modes *versus* different thicknesses of perovskite emissive layer for vertical oriented TDMs and horizontally oriented TDMs is depicted in Fig. 5d and e. The power fraction of the surface plasmon mode of horizontal TDMs is quenched significantly, and the out-coupled efficiency of the trapped mode improved as compared with the vertical TDMs. Notably, the efficiency of PeLEDs can be propelled up to 50% with preferential orientation of the anisotropic perovskites materials with in-plane orientation of TDMs (Fig. 5f). Thus, anisotropic materials could yield an improved outcoupling efficiency owing to the reduction of trapped light and the eradication of the non-radiative recombination losses.

The anisotropic emitter has raised the efficiency of LEDs by more than 40%, owing to high horizontal-to-vertical dipole ratios. Cui *et al.* reported that 84% horizontally oriented TDMs are expected from ensemble perovskite nanoplates and yield 31% outcoupling efficiency (anisotropic film), which is higher than that from the isotropic emitter ($\sim 23\%$).⁹⁴ The large portion of horizontally oriented TDMs boosted the EQE of LEDs to 23.6% and a maximum brightness of 3140 cd m^{-2} . Additionally, by carefully optimizing the horizontally oriented TDMs, the LEDs efficiency could be increased to the upper level of $\sim 40\%$.⁹⁴

Kumar *et al.* reported that controlling the aspect ratio of the anisotropic nanocrystal superlattices perovskite emitter is essential to enhance the light outcoupling in PeLEDs.⁷⁹ They claimed that, for a given dipole, the emission radiative rate is the product of the transition dipole moment (\mathbf{p}) and local electric field (\mathbf{f}) vectors, *i.e.*, $(\mathbf{p}\cdot\mathbf{f})^2$. Under the assumption of the isotropic TDM orientation, Θ_{IP} is given by eqn (3),

$$\Theta_{\text{IP}} = \frac{2f_x^2}{2f_x^2 + 2f_z^2} \quad (3)$$

As shown in Fig. 6a, the local electric field distribution (f_i) strongly depends upon the shape of individual nanocrystals, *i.e.*, cuboids and spheroids with different aspect ratios. For instance, spheroids and cuboid nanocrystals where $f_x = f_y$ and aspect ratio = 1 show an isotropic polarization response (out-of-plane response) with Θ_{IP} of around 67%. On the other hand, anisotropic nanocrystals in the current investigation have the in-plane distribution of the local electric field. For

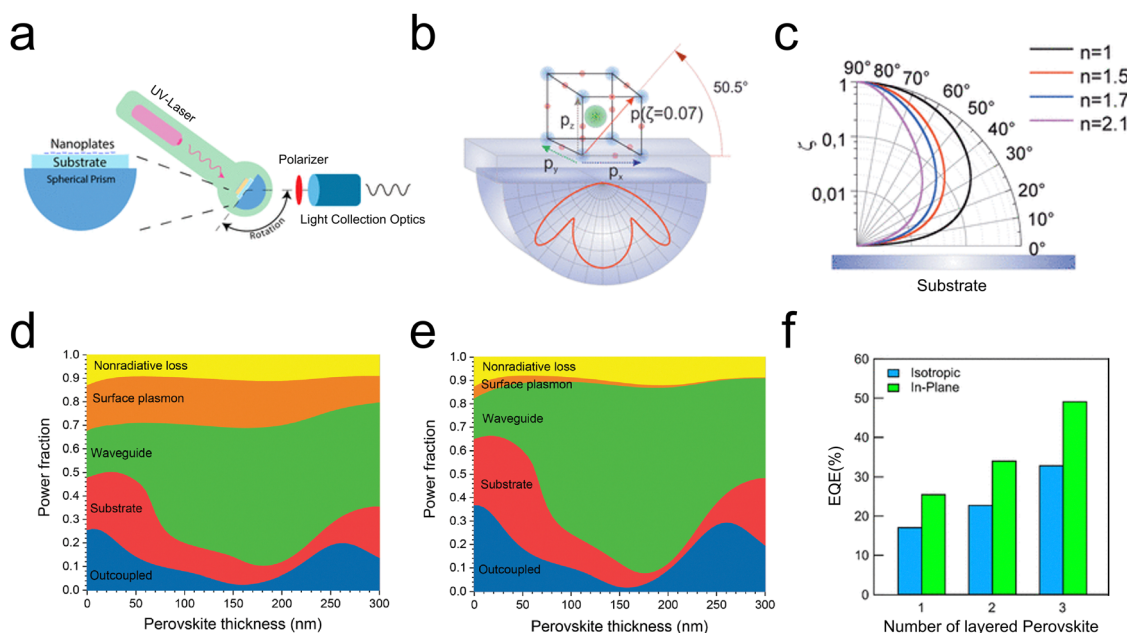


Fig. 5 (a) Measurement setup for angle-dependent PL. Reproduced with permission.⁹⁷ Copyright 2019, American Chemical Society. (b) The value of the alignment constant determined the angle of the transition dipole moment vector. (c) The value of the alignment constant (ζ), and the refractive indices dependent profile. Reproduced with permission.⁹⁶ Copyright 2017, American Chemical Society. (d and e) Power distribution into different optical modes of PeLEDs with various perovskite layer thicknesses for (d) isotropic dipole orientation ($\theta = 0.33$) and (e) horizontal dipole orientation ($\theta = 0$). Reproduced with permission.⁹⁸ Copyright 2020, The Optical Society. (f) Simulated in-plane or out-of-plane oriented TDMs distribution *versus* efficiency for PeLEDs. The n represents layered perovskites quantum-wells. Reproduced with permission.⁹⁹ Copyright 2020, American Chemical Society.

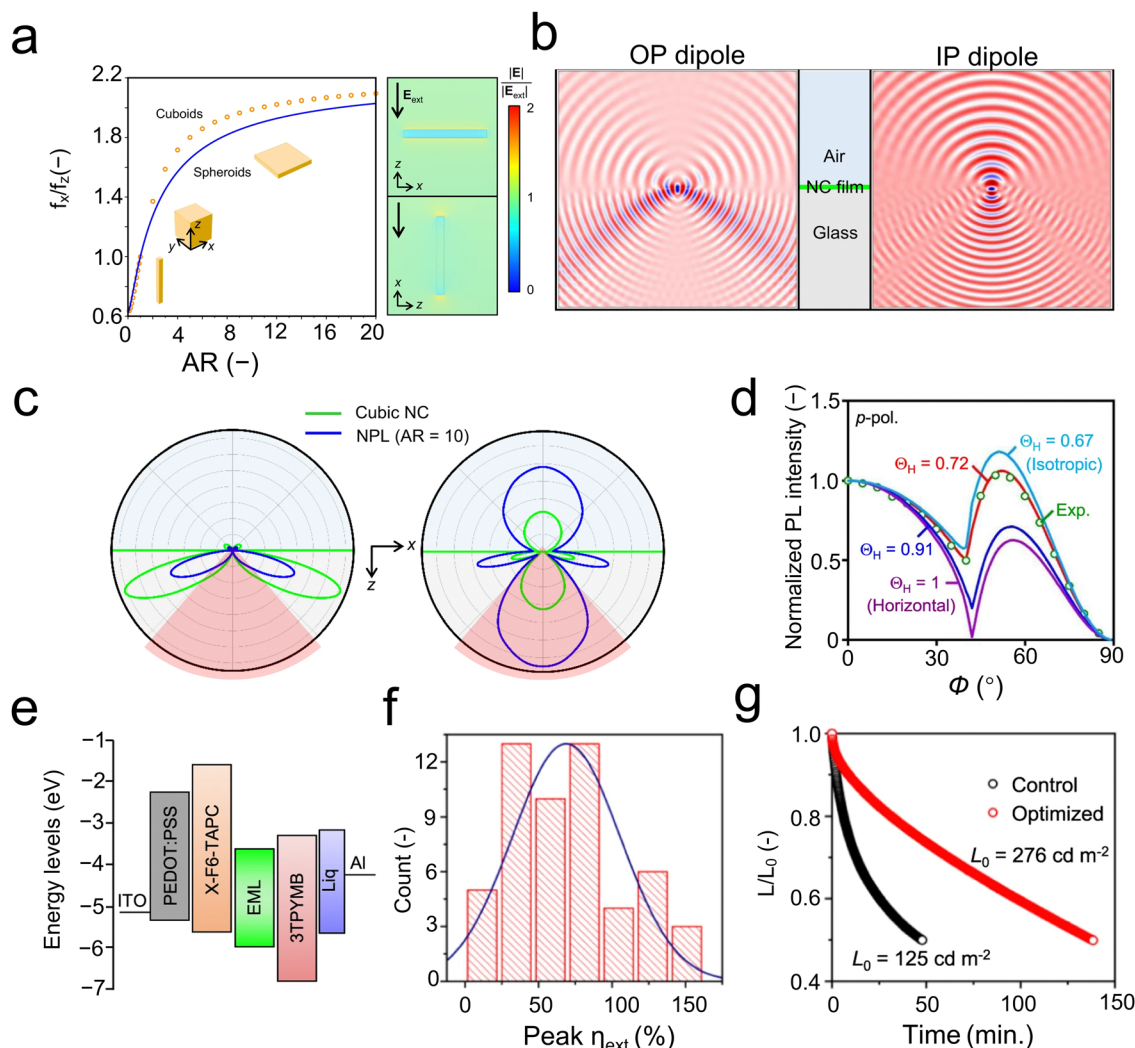


Fig. 6 (a) Calculated ratio of horizontal (x) to vertical (z) local field factor, f_x/f_z , as a function of the aspect ratio. Calculated electric field intensity profiles (b) and radiation patterns (c) in the x - z plane for an out-of-plane (OP; left) and in-plane (IP; right). (d) Angle-dependent PL. (e) Schematic illustration of PeLEDs, and (f and g) optoelectronic properties of PeLEDs. Reproduced with Permission.⁷⁹ Copyright 2022, Nature Publishing Group.

anisotropic nanocrystals, Θ_{IP} is around 90% for aspect ratio ~ 30 . Fig. 6b and c represents the distribution of the radiation patterns of the in-plane and out-of-plane anisotropic nanocrystals. Fig. 6d illustrates the experimentally obtained angle-dependent PL. The value of Θ_H is 0.67, 0.72, and 0.91 for isotropic, anisotropic nanocrystals, and aspect ratio $\rightarrow \infty$ models, respectively. The schematic illustration of the fabrication PeLEDs based on anisotropic nanocrystals ($\Theta_H \sim 72\%$) is shown in Fig. 6e. The optoelectronic properties of PeLEDs are depicted in Fig. 6f and g, in which the maximum luminance of 5009 cd m^{-2} , maximum efficiency of 24.96%, and operation stability of 150 h were reported based on these anisotropic nanocrystal superlattices, owing to the enhanced outcoupling efficiency.

2.3. Control of crystallinity of perovskite layer

The outcoupling efficiency of PeLEDs can be manipulated with the control of the crystallinity of the perovskite EML, as a high

crystalline thin film also induces a preferentially oriented emission.¹⁰⁰ In addition, the highly crystalline perovskite thin film has uniform surface morphology, reduced defects, and a well-organized, orderly packed surface, which can avoid non-radiative decay and induce efficient light emission. In recent years, strategies using additive and template-assisted growth have been explored to improve the crystallinity of perovskite EML, including metal halides, organic molecules, and ammonium halides.^{101–106}

2.3.1. Additives-assisted growth. The perovskite crystallinity can be tailored with an additives-assisted growth strategy, which is also essential for the resultant device performance. For example, Zhu *et al.* reported the vertical orientation of FAPbI₃ with an additive-assisted method using multifunctional groups, 2-(2-(2-aminoethoxy)ethoxy)acetic acid.¹⁰⁷ The schematic illustration of introducing pentane-1-amine (PAM) and pentanoic acid (PAC) in the 3D FAPbI₃ precursor solution is depicted in Fig. 7a and b. The precursor solution containing the molar ratio

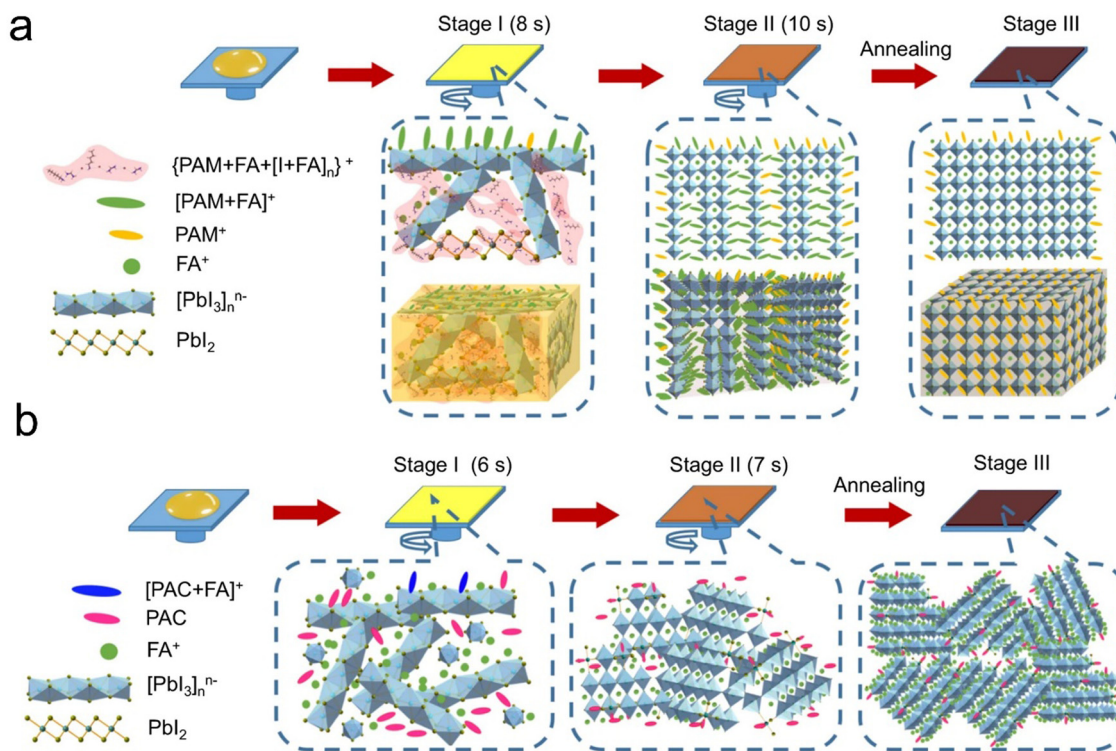


Fig. 7 (a) Pentane-1-amine-assisted oriented growth. (b) Isotropic growth with pentanoic acid additive. Reproduced with permission.¹⁰⁷ Copyright 2021, Nature Publishing Group.

of x : 2.4 : 1 (x : PAM, PAC) was spin-coated and heated at 100 °C for 20 min for 3D FAPbI₃ thin film formation. The surface morphology analysis of the additive-assisted (pentane-1-amine and pentanoic acid) method reveals that the perovskite layer is well-connected and has a regular-shaped grain, contrary to the control film. Significantly, the faceted shape of the crystallites was obtained using a pentane-1-amine-based additive. Regular and large grain perovskite grains become more regular, owing to a strong hydrogen bond network (PAM + FA + I [FA + I]_n)⁺ (Fig. 7a stage I). The low purity of FA⁺ and PAM⁺ additive acts as a template for the vertical growth of perovskite due to standing order along the interface between the perovskite and air, boosting the continuous vertical growth of the pentane-1-amine-based perovskite crystal (Fig. 7a stage II). After the intermediate (stage II), the annealing process results in well-organized in-plane growth of a perovskite crystal (stage III). On the other hand, it was observed that the weak interaction between pentanoic acid and FA led to earlier crystal growth and randomly oriented perovskites (Fig. 7b, stage I–III). The optoelectronic properties of the PeLEDs (ITO/polyethylenimine ethoxylated (PEIE)-ZnO/EML/TFB/MoO_x/Au; 60 nm) based on pentane-1-amine- and pentanoic acid-additive were investigated. The efficiency of 14.2 ± 0.9 and 12.5 ± 1.2% and half-lifetime (T_{50}) of 9.5 and 5.4 h for pentane-1-amine- and pentanoic acid-additive were realized, respectively. It was noticed that for the discrete crystallinity of 3D FAPbI₃ with multifunctional groups, 2-(2-(2-aminoethoxy)ethoxy)acetic acid-additives, the outcoupling efficiency could be improved to 29.1 ± 2.4%.

A radiance of 250 W sr⁻¹ m⁻² and peak efficiency of over 22.2% were also reported with 2-(2-(2-aminoethoxy)ethoxy)acetic acid-additives assisted growth.

Additionally, Cao *et al.* successfully showed effective electroluminescence from solution-processed perovskites that have a tendency to form submicrometre-scale structures by introducing amino-acid additives (Fig. 8a).³⁸ The formation of the discrete submicrometre-structure perovskite involves faceted platelets with roughly rectangular shapes. The platelets are randomly tiled on the substrate, and the size of the platelets is between 100 nm and 500 nm (Fig. 8b). As shown in Fig. 8a, the wide-angle light (ray A) can enter the low-index organic layer and propagate into the glass substrate. The 3D finite-difference-time-domain (3D-FDTD) simulations were further carried out to analyze the outcoupling efficiency in the 3D perovskite film and submicrometre platelets. The results show that a 3D perovskite device with a continuous and flat emitting layer has an outcoupling efficiency of 21.8%. Surprisingly, the outcoupling efficiency of a device with submicrometre-structures reaches about 30%.

Furthermore, the crystal orientation is essential for the high-quality perovskite 3D film, which reduces the surface defect density and increases the surface coverage owing to well-organized packed crystals.¹⁰⁸ As schematically illustrated in Fig. 9, the temperature range between 35–40 °C was considered an ideal value for preferential orientation along the (110) crystal plane, and to avoid the fast crystallization process associated with the solution-processed 3D perovskite film. The translated

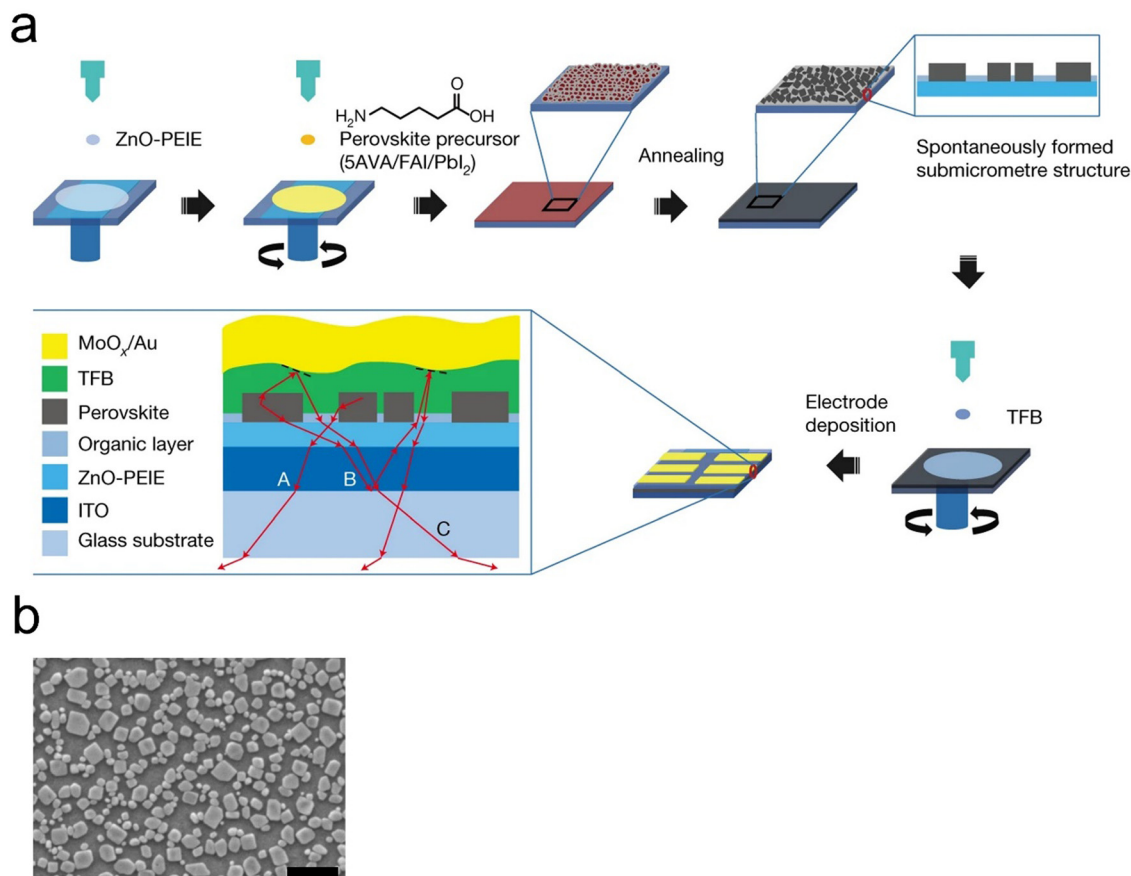


Fig. 8 (a) Fabrication of the device and formation of the submicrometre-structure. Rays A, B and C, representing light trapped in devices with a continuous emitting layer, can be extracted by the submicrometre-structure. (b) SEM image of the submicrometre perovskite. Reproduced with permission.³⁸ Copyright 2018, Nature Publishing Group.

PeLEDs of this highly oriented perovskite film exhibit a high brightness of $79\,932\text{ cd m}^{-2}$, external efficiency of 16.45%, and T_{50} of 136 h at an initial luminance of 100 cd m^{-2} . Thus, crystal orientation along the (110) crystal plane and uniform surface coverage in the temperature range of 35–40 °C is an exciting way to manipulate the fast-crystallization process to enhance the PeLEDs performance.

2.3.2. Template-assisted growth. The control of the growth of perovskite has a profound impact on the quality of the perovskite film. A well-growth crystalline perovskite layer contains excellent film quality with reduced defect density, smooth surface morphology, and preferred orientation, leading to achieving high-performance PeLEDs. Regarding the points, template-assisted growth provides an ideal approach to realizing orientated nanostructures with a preferential orientation accomplished with enhanced light extraction in PeLEDs.

It was recently noticed that the hydrophobicity of the glass substrate had impeded the highly crystalline growth in the perovskite film.¹⁰⁹ Lowering the hydrophobic nature of the bottom layer or glass substrate is necessary to realize crystalline perovskite film growth. There have been numerous reports on the nature of the bottom layer. For example, Xiao *et al.* reported a highly uniform, ultra-flat perovskite film on the plasma-etched

hole transporting layer.¹¹⁰ The fabricated PeLEDs delivered a high brightness of 1200 cd m^{-2} , EQE of 10.4%, and significantly improved the shelf operation stability in a controlled environment. It should be noted that the optimized time for plasma etching is 2–6 s. Beyond this limit, the surface of HTL could become damaged, resulting in deteriorated electronic properties.¹¹¹

Additionally, the *in situ* grown thickness-controlled quantum-well CsPbBr₃ on a thin layer of poly(9-vinyl carbazole) (PVK) growth template was also reported.¹¹² This template facilitated the low trap densities, high PLQY, and well-defined surface morphology and oriented crystal along the [020] planes parallel to the substrate surface, resulting in high-color-purity PeLEDs with a full width at a half maximum (FWHM) of 82 meV, yielding a maximum brightness of $\sim 14\,000\text{ cd m}^{-2}$ at 8 V with external efficiency exceeded from 10.4%. However, such growth templates hamper the device fabrication's reliability owing to the solubility of PVK in *N,N*-dimethylformamide (DMF), and dimethylsulfoxide (DMSO) leads to the mixing of PVK with perovskite. To avoid the above issue, a thin layer of polymer (polyvinylpyrrolidone, PVP) coating on the HTL may allow for protection and prevent the intermixing of HTL with the perovskite film. Thus, Kong *et al.* addressed an approach to

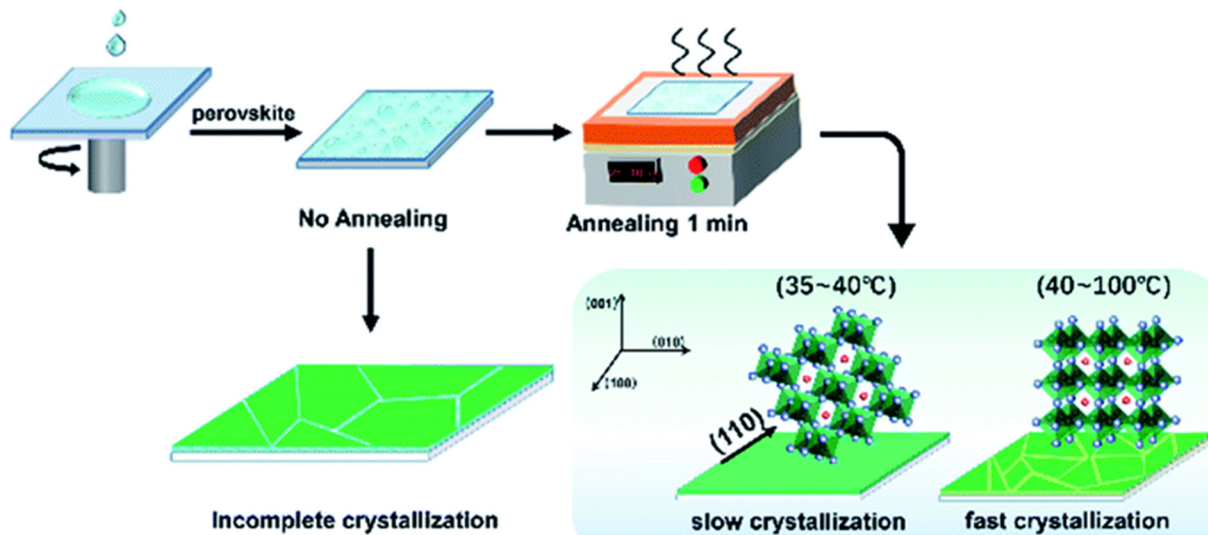


Fig. 9 Schematic illustration of the oriented growth of the perovskite with slow (35–40 °C) and fast (40–100 °C) crystallization strategy. Reproduced with permission.¹⁰⁸ Copyright 2021, Royal Society of Chemistry.

accomplish the energy transfer pathway in perovskite films using methanesulfonate on a pre-deposited thin layer of PVP growth template.¹¹³ The quasi-2D perovskite is reconstructed owing to methanesulfonate interaction with the spacer butylammonium cations *via* strong hydrogen bonding, which raises the energy acceptor-to-donor ratios and increases the energy transfer in perovskite films. Their approach leads to a current efficiency of 63 cd A⁻¹, a peak luminance of 13 400 cd m⁻² at a low applied voltage of 5.5 V, and 20.5% external quantum efficiency.

Although such a high efficiency was reported, the solvent selection for PVP and HTL should be unique. Otherwise, intermixing of PVP and HTL could occur, which would deteriorate the bottom layers. Another strategy to eradicate the issues mentioned above was reported for the formation of high-quality perovskite films *via* the application of a thermally evaporated ultrathin layer (1 nm) of lithium fluoride (LiF) growth template.⁶⁹ This growth template enabled the formation of high-quality perovskite films aligned parallel to the substrate normal (*i.e.*, preferred oriented along the [020] planes to the substrate surface). Hence, the oriented perovskite films exhibit a PLQY of 65%, and an efficiency of 19.1% with ultrahigh brightness of over 1500 cd m⁻² was reported from PeLEDs.⁶⁹ The tedious fabrication of 1 nm LiF in an ultrahigh vacuum is a major stumbling block.

The oriented perovskite film enables a high outcoupling and a high-color purity with a narrow emission spectrum, which is anticipated to apprehend a wide color gamut in high-resolution displays. The highly aligned three-dimensional MAPbBr₃ film in the [001] direction can be obtained from a quasi-two-dimension perovskite growth template composed of phenylethylammonium lead bromide (PEA₂PbBr₄).¹¹⁴ The reference 3D bulk and 2D films are scattered with large separated cubic crystals (Fig. 10a, stage I–II). Contrary to their counterparts, the ion exchange conversion of 2D into a 3D MAPbBr₃ film appeared

to be closely placed plate-like crystallites (Fig. 10a, stage III). Notably, the reduced crystallographic defect density and well-organized oriented film resulted in ultranarrow electroluminescence spectra with an FWHM of 15.3 nm and color purity of 98.1% among the reported organic-inorganic green PeLEDs. Transient optical outcoupling experiments predicted that the excitons are dissociated into electron–hole significantly at lower-energy states within ~1 ps. The observed ultrafast transition of excitations limits the possibility of non-radiative recombination rates, promoting radiative emission through a bimolecular channel, leading to the efficiency of up to 20.1%, highest luminance of 945 cd m⁻² with operation stability of $T_{50} = 46$ h in the air at peak EQE.

The interaction of small organic cations such as 2-phenylethylammonium with 3D polycrystalline film transformed the 3D into 2D layered perovskite films.¹¹⁵ During the process, the implementation of solvent vapor annealing resulted in well-organized oriented micrometer-sized nanoplatelets (Fig. 10b). The emergence of (00 l) peaks in surface analysis strengthens the understanding of the out-of-plane orientation of quasi-two-dimensional perovskites. These well-organized oriented nanoplatelets-based 2D layered perovskites not only enhance the crystallinity, but the photophysical properties are also improved. PeLEDs showed low subthreshold leakage currents and significantly high efficiency, demonstrating a pure violet emission (Fig. 10c and d).¹¹⁵

2.4. Film thickness

The outcoupling efficiency can be managed by the thickness of the perovskite emissive layer and bottom transparent conductive ITO anode. The EML and ITO thickness significantly impact the density of trapped light within optical modes (waveguide and substrate mode) owing to the divergence of refractive indices. The waveguide loss in PeLEDs configuration is substantial due to high n values. Thus, the optimized

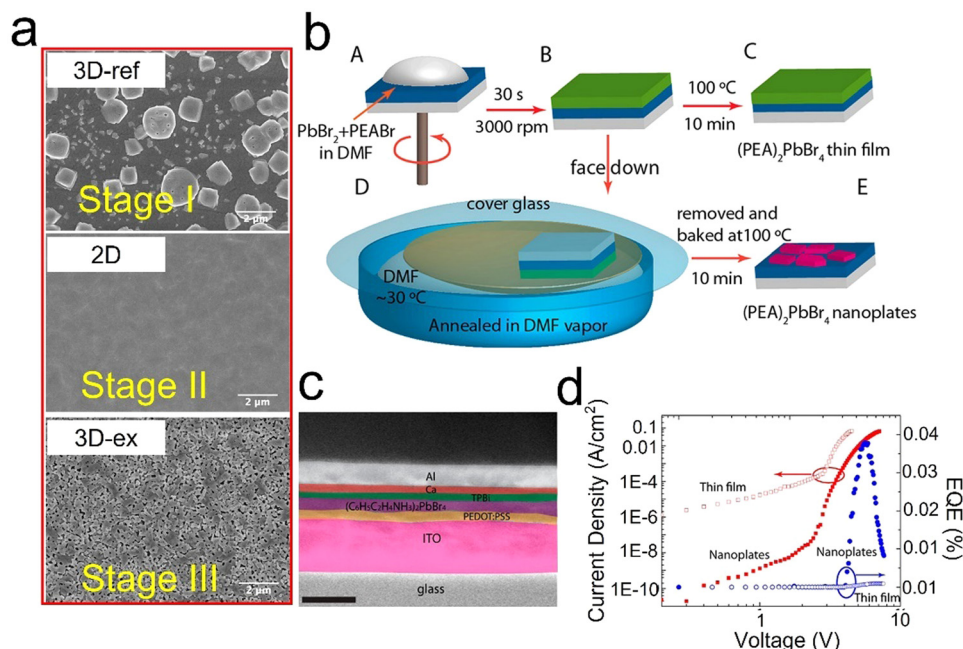


Fig. 10 (a) Scanning electron microscopy (SEM) image of the 3D reference (stage I), 2D (stage II), and converted 3D film from the 2D template (stage III). Reproduced with permission.¹¹⁴ Copyright 2018, American Chemical Society. (b) Synthesis of $(\text{PEA})_2\text{PbBr}_4$ thin films and nanoplates on PEDOT:PSS-coated ITO substrates. (A and B) A DMF solution of 2 : 1 2-phenylethylammonium bromide and PbBr_2 is spin-coated onto a PEDOT:PSS (blue)-coated ITO substrate (gray). The spin-coated film was either directly baked at 100 °C for 10 min to prepare polycrystalline $(\text{PEA})_2\text{PbBr}_4$ thin films (C), or annealed in DMF vapor (D) and then baked at 100 °C for 10 min to prepare (E) micrometer-sized $(\text{PEA})_2\text{PbBr}_4$ nanoplates (purple). (c and d) Cross-sectional SEM image and J - V dependence (red symbols) and EQEs (blue symbols) for LEDs. Reproduced with permission.¹¹⁵ Copyright 2016, American Chemical Society.

thickness of the EML can effectively suppress waveguiding and improve light outcoupling. For example, 9 nm thick ensemble perovskite nanoplates yielded a 31% outcoupling efficiency and PeLEDs efficiency of more than 23.6%.⁹⁴ Additionally, by carefully optimizing the optical constant and film thickness, external efficiency could be increased to the upper level of ~40%.

Zhao *et al.* reported that the optimized thickness of EML is 35–50 nm to acquire the efficiency of 17.6% for 40 nm $\text{Cs}_{0.2}\text{FA}_{0.8}\text{PbI}_{2.8}\text{Br}_{0.2}$, 14.3% for 35 nm MAPbI_3 , 10.1% for 40 nm FAPbI_3 , and 11.3% for 50 nm FAPbBr_3 -based PeLEDs (Fig. 11a–e).⁸¹ The optical simulations were performed to understand the primary origin of the improved EQE using a thinner perovskite emitting layer (Fig. 11f). The simulation results further verify the experimental observations, and the optimal outcoupling efficiency occurs with perovskite thicknesses in the range of 35–40 nm, where the waveguide mode loss is minimized. Jung *et al.* also analyzed the efficiency and thickness characteristics to compensate for the high n value of ITO and EML.¹¹⁶ The optical simulation reveals that an efficiency of 25% could be achieved with an identical thickness of both ITO and perovskite emissive layer (~20 nm). However, achieving stable electrical conductivity and reproducibility with 20 nm thick ITO is challenging. Thus, a 200 nm thick ITO layer and 30 nm perovskite EML with an obtained EQE of 21% were used to lower the density of trapped light within the substrate and waveguide modes.

More importantly, the outcoupling efficiency can be increased by further thinning the emissive layer by about 10 nm.¹¹⁷ The thin emissive layer reduces the refractive index of the functional layers, essentially decreasing the fraction of light trapped in the waveguide modes. This ultra-thin regime enables the enhancement of the EQE to over ~30% without the need for a complex photonic structure, as illustrated in Fig. 12. They performed the theoretical investigation by employing an ITO-coated (thickness 150 nm) glass anode coated with poly-(3,4-ethylenedioxythiophene):polystyrene (PEDOT:PSS, 20 nm)/poly(bis(4-phenyl)(2,4,6-trimethylphenyl)amine) (PTAA, 20 nm) hole injection/transport layers and 2,2',2''-(1,3,5-benzinetriyl)-tris(1-phenyl-1-*H*-benzimidazole) (TPBi) (45 nm) electron transport layer covered with a LiF/Al (1 and 100 nm respectively) cathode. Notably, the simulation results in Fig. 12b shows that for a 35–60 nm thick emissive layer, the maximum attainable EQE reaches ~21–22%. On the other hand, reducing the emissive layer to close to 10 nm ultimately enables one to boost the EQE to over ~30%. By thinning the emissive layer, there will be a significant reduction in the amount of light trapped in the waveguiding mode due to the decreased effective refractive index of the functional layers (Fig. 12d).

2.5 Photon re-absorption in a thick perovskite layer

The efficiency of PeLEDs has surpassed the limit of 30% EQE, despite the high discrepancy of refractive indices ($n \approx 2.0$ –2.6) and isotopically oriented perovskites emissive layer being

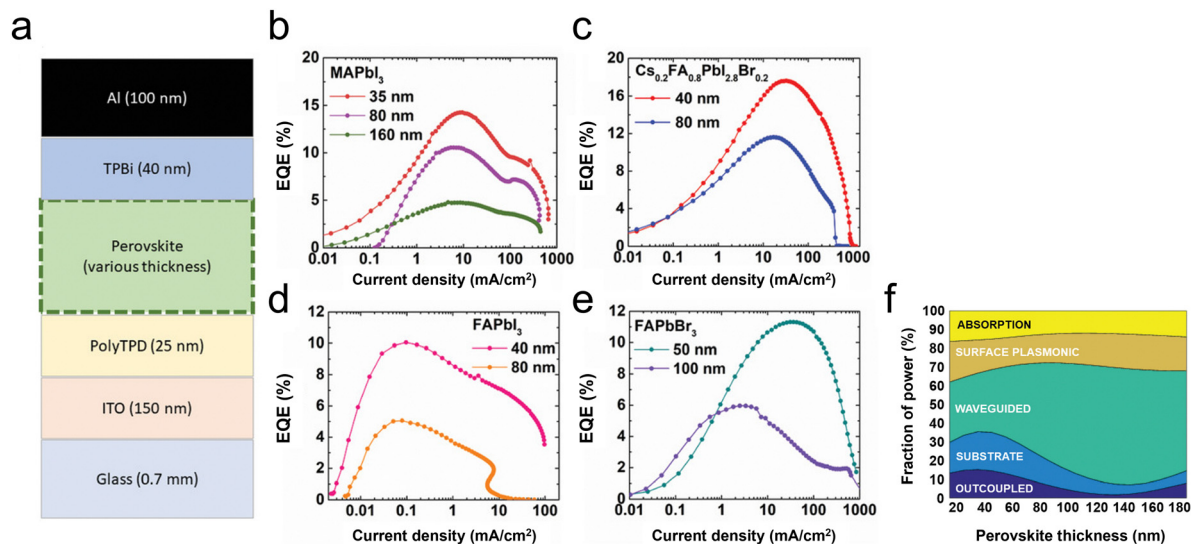


Fig. 11 (a) Device configuration of PeLEDs. (b–e) The efficiency and current density curves of EML with different thicknesses. The optimized thickness of EML is 35–50 nm to acquire the efficiency of 17.6% for 40 nm $\text{Cs}_{0.2}\text{FA}_{0.8}\text{PbI}_{2.8}\text{Br}_{0.2}$, 14.3% for 35 nm MAPbI_3 , 10.1% for 40 nm FAPbI_3 , and 11.3% for 50 nm FAPbBr_3 -based PeLEDs. (f) Optical power distribution analysis versus perovskite emitting layer thickness PeLEDs. Reproduced with permission.⁸¹ Wiley-VCH.

surprisingly above the threshold level, which the classical ray-optics theory for outcoupling predicts (7–13%).⁷⁸ This higher

efficiency beyond the expected value shall be probed with a photon-recycling process that significantly increases the

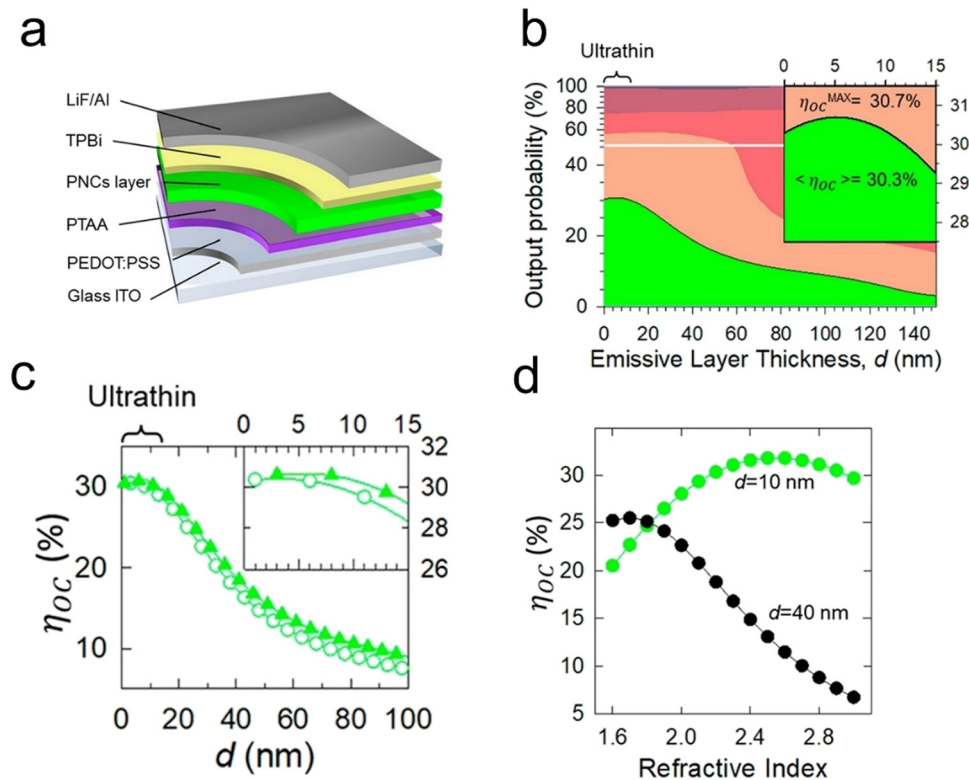


Fig. 12 (a) Schematic depiction of PeLEDs with the architecture used for the light outcoupling simulation. (b) Outcoupling probability distribution as a function of the thickness of the emissive layer, thickness (d), for PeLEDs with the same structure as in panel a. The output probability depends strongly on the refractive index and thickness of all functional layers. (c) Comparison between outcoupling (η_{OC})-values vs. thickness computed by considering (triangles) or excluding (circles) photon recycling effects. (d) η_{OC} as a function of the refractive index of ultrathin ($d = 10$ nm, green circle) and standard ($d = 40$ nm, black circles) active layer thickness. Reproduced with permission.¹¹⁷ Copyright 2023, American Chemical Society.

outcoupling efficiency of trapped light between different optical modes (waveguide and substrate mode) with sequential re-absorption and re-emission of photons at high radiation efficiency. Notably, a thick perovskite layer dominates this effect. The exceptionality of the photon-recycling process remains distinctive in perovskites owing to the small Stokes shift, which contributes 70% to the overall emission.⁸⁰ Recent reports show that the outcoupling efficiency can be triggered with the photon-recycling process by re-absorption and re-emission events for given excitations to tailor the photon management from trapped to outcoupling mode.⁶⁵ Moreover, quantitative analysis showed that an efficiency of 30–50% can be achieved through reduced refractive indices, materials engineering, re-absorption, and effectively eliminating the parasitic absorption through transparent conductive electrodes. Additionally, an efficiency of over 90% is also attainable because of the suppression of parasitic absorption and maximize the photon-recycling effect with an improved device configuration (Fig. 13a and b). Recently, Zhengguo *et al.* revealed that the thickness-dependent photon-recycling process in a thin film and PeLED device occurs.⁸⁰ The photon-recycling zone in the entire PeLED device is wider owing to the isotropic random EL emission, contrary to the thin film that is confined in an angle of 38.7° (θ_{glass}) (Fig. 13c). The photon-recycling contribution in 30 nm and 2200 nm thick EML is 0.6–2.4% and 40.4%, respectively (Fig. 13d and e). The theoretical analysis shows that all photons are recycled more than once on average before they are outcoupled. The extraordinarily thick (2200 nm) perovskite EML PeLEDs acquired an efficiency of 15.3% owing to

the photon-recycling process. Recently, T.-W. Lee's group reported a simple method to produce *in situ*-formed core/shell nanocrystals by reacting 3D perovskite films with benzyl phosphonic acid.³⁷ The benzyl phosphonic acid treatment separates the 3D perovskites (205 ± 97 nm) to form core/shell perovskite nanocrystals (10 ± 2 nm) (Fig. 14a–c). The trap density was significantly reduced, and the radiative recombination efficiency was substantially enhanced. The 270 nm thick *in situ* core/shell EML PeLEDs showed a maximum EQE of 28.9%, luminance of $470\,000$ cd m^{-2} , and half-lifetime of 520 h at an initial brightness of 1000 cd m^{-2} . Additionally, optical simulation verified that PeLEDs could reach an EQE of 29.2% with the photon-recycling effect (Fig. 14d).

Consequently, Richard H. Friend, Dawei Di, Felix Deschler, and Neil C. Greenham discussed⁷⁸ (a) how ray-optics limits can be suppressed to obtain an efficiency above 20%; (b) what internal quantum efficiency and light extraction efficiencies are being secured in current planar PeLEDs; and (c) how to estimate the upper-efficiency limit of current PeLEDs devices that can be answered owing to the photon-recycling process.

3. Future perspectives

In this review, we have primarily summarized the recent developments in light extraction management in PeLEDs based on theoretical and experimental analyses. Although the abundant strategies, including surface passivation, ligand engineering, cation/anion mixing, and utilizing the efficient energy funneling

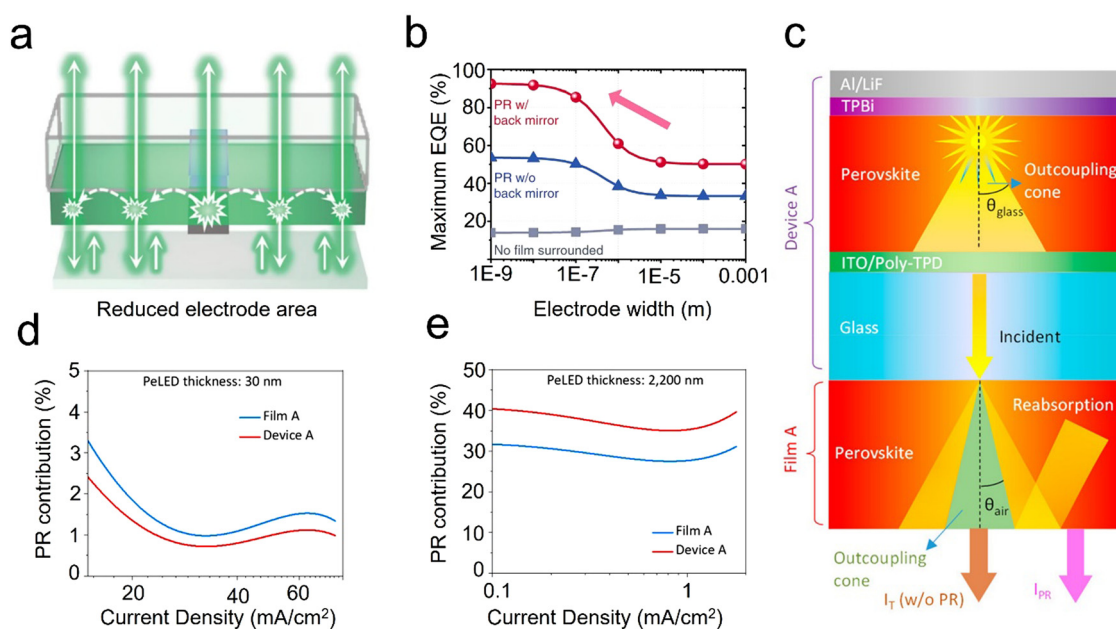


Fig. 13 (a) A proposed LED architecture consists of small area electrodes and a large area film, with a reflecting mirror at the bottom. (b) Calculated maximum EQE (IQE = 100%) as a function of the electrode width in the proposed systems having photon-recycling with a back mirror, photon-recycling without a back mirror (only front re-emission is collected), and no film surrounded (photon-recycling only occurs inside the pixel). Reproduced with permission.⁷⁸ Copyright 2020, Nature Publishing Group. (c–e) Schematic diagram of the photon-recycling zone difference in device A and film A. (d and e) Photon-recycling contribution in film A and real PeLEDs (device A) with a thickness of 30 nm (d) and 2200 nm (e). Reproduced with permission.⁸⁰ Copyright 2021, American Chemical Society.

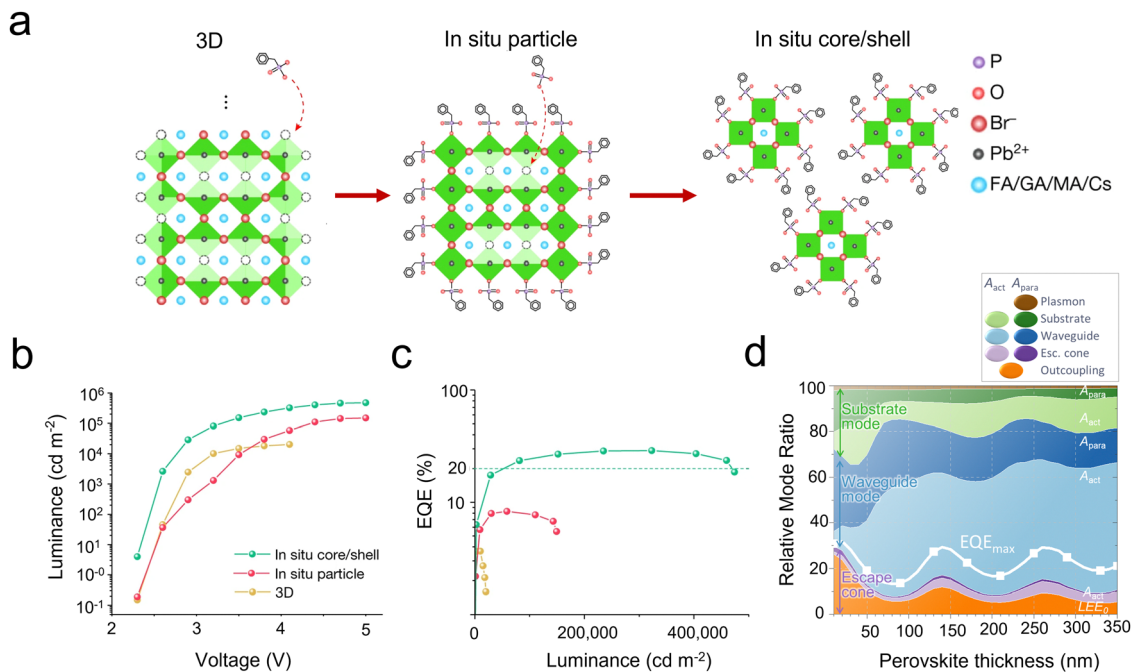


Fig. 14 (a) Schematic illustration of the transformation process of 3D (left) into *in situ* particles (middle) and *in situ* core/shell (right) structures by benzyl phosphonic acid treatment. FA, formamidinium; GA, guanidinium; MA, methylammonium. (b and c) Luminance versus voltage and EQE versus luminance curves of PeLEDs. (d) Calculated maximum EQE considering the effect of photon-recycling as a function of perovskite thickness. Background colors represent the fractions of outcoupling, waveguide, substrate, and plasmon modes per each condition. Non-outcoupled photons are re-absorbed by either perovskite (A_{act}) or parasitic layers (A_{para}). Reproduced with permission.³⁷ Copyright 2022, Nature Publishing Group.

of 2D layered structure perovskites, have advanced the internal quantum efficiency to more than 90%, an EQE beyond the 20% limit and operational stability owing to a large portion of photon trapping within the thin layer of PeLEDs stack remains and impedes further advancements. Undoubtedly, the remarkable properties of perovskites, including the high PLQY, narrow emission peak, small Stokes Shift, and facile synthesis at a lower temperature, encourage the development of high-performance PeLEDs, which is an inevitable trend of practical applications. Nevertheless, the low operational stability, isotropically oriented emitters, refractive indices discrepancy, and high non-radiative losses owing to poor film coverage and thickness are the few detrimental factors limiting the outcoupling efficiency. Based on the existing literature, we have reviewed the outcoupling management in pattern-nanostructures photonics (quantum wires), vertically oriented quasi-2D perovskites, high-index grading, and anisotropically oriented nanoplatelet emitters (high horizontal dipole ratios of more than 76%). Finally, we have postulated a few strategies for outcoupling efficiency management by examining the photon-recycling process and thickness management in ITO and EML.

The anisotropic emitter has raised the modern OLED efficiency by more than 40% due to the high horizontal-to-vertical dipole ratios. Due to the high density of outcoupled photons, the anisotropic emitter with in-plane TDMs would be advantageous for PeLEDs. Sargent *et al.* quantified the directional emissions from 2D perovskites and revealed that in single crystals, transition dipoles are oriented in-plane (>90). The trade-off

between the film thickness and emission anisotropy decreases as the nominal layer thickness increases. Further, theoretical analysis shows that the PeLEDs efficiency of 45% can be obtained from a 2D perovskite ($n = 3$) owing to a reduction in the surface plasmon modes at the cathode interface, which is excited only by transverse magnetic (TM) polarizations and in emission into waveguided modes.⁹⁹ The outcoupling efficiency of more than 31% was reported from a monolayer of face-on oriented nine nm thick nanoplatelets. The high horizontal dipole ratio is 84% from an *in situ*-grown perovskite film, leading to an external quantum efficiency of 23.6%.⁹⁴ The horizontal dipole ratio of 75% was reported from colloidal anisotropic nanocrystals. The thin film of colloidal anisotropic nanocrystals exhibited a theoretical outcoupling efficiency of 30%, and the 30 nm thick EML demonstrated an external efficiency of 24.96%. All the above strategies have demonstrated emission anisotropy from thin EML layers and photon extraction management.

The divergence of refractive index between the electron-injecting layer, EML, hole-injecting layer, and substrate subsequently leads to optical losses owing to different optical modes such as waveguide mode, substrate mode, and evanescent mode. The discrepancy of refractive indices in state-of-art-LEDs technologies is not very apparent ($n \approx 1.8$ for transporting layers and EML). Few reports have been pertinent to overwhelming the trapping of light within LED structures, such as rational design nanostructures, high index-grading, ligand engineering, pre-deposit polymer-assisted method, and moth-eye

nanostructures. For example, effective outcoupling management can be obtained by eliminating the optical losses associated with the waveguide mode by embedding an imprinted bioinspired moth-eye nanostructure at the perovskites anode interface.⁸⁷ The 3D anodic alumina membranes and randomly distributed nanohole array nanophotonic substrates were also explored for outcoupling management. These approaches have enabled the significant reduction of the density of trapped electroluminescence within the PeLEDs devices, leading to efficient outcoupling improvement and enhanced quantum efficiency.^{85,86}

More importantly, thinning the emissive layer can increase the outcoupling efficiency. The thin emissive layer reduces the refractive index of functional layers, essentially decreasing the fraction of light trapped in the waveguide modes. This ultra-thin regime enhances the EQE to over $\sim 30\%$ without needing a complex photonic structure.

Vertically oriented 2D perovskites have emerged as contenders for optoelectronic devices due to strong dielectric- and quantum-confinement effects owing to large exciton binding energy with quantum well nature and high PLQY. Additionally, the graded energy structures in quasi-2D perovskites are an efficient method for successfully manipulating radiative recombination rates, pattern-nanostructures, and submicrometre-size perovskite crystals have played an essential role in outcoupling management.¹¹⁸ Moreover, the outcoupling efficiency of PeLEDs can be manipulated with the crystallinity of the perovskite EML layer. The highly crystalline perovskite EML layer has uniform surface morphology, reduced defects, and a well-organized, orderly packed surface, leading to adequate device performance.¹⁰⁰

A complete understanding of EML and ITO thickness is also necessary. It has been shown that an extraction efficiency of 21% could be achieved with an ITO and EML thickness of ~ 200 nm and ~ 30 nm, respectively. The efficiency of PeLEDs over the 20% limit, despite the high discrepancy of refractive indices ($n \approx 2.0$ – 2.6) and isotopically oriented perovskites emissive layer (vertically oriented TDMs), is surprisingly above the threshold level, which the classical ray-optics theory for outcoupling predicts (7–13%).⁷⁸ This efficiency limit beyond the predicted value shall be probed with a photon-recycling process that significantly increases the outcoupling efficiency of trapped light between different optical modes (waveguide and substrate mode) with sequential re-absorption and re-emission of photons at high radiation efficiency. The exceptionality of the photon-recycling process remains distinctive in perovskites owing to the small Stokes shift, which contributes 70% to the overall emission.⁸⁰

We have noticed that photon-recycling, high horizontal dipole ratios, vertically oriented 2D perovskites, and pattern nanophotonics have resulted in photon extraction management. Anisotropic nanocrystal superlattices with a high horizontal dipole ratio of $>85\%$ could achieve more than 30% EQE owing to the high photon out-coupling efficiency. By effectively employing the TDMs, operational stability can also be improved.⁷⁹ Precise theoretical works are required to encompass oriented TDM ratios, photon-recycling process, and film thickness to further enhance the photon extraction process. Of course,

this procedure requires years to mature. This review on oriented PeLEDs outcoupling efficiency management could provide a feasible stance for the future development of anisotropic emitters for practical applications.

4. Conclusions

In this review, we have primarily summarized the recent developments in light extraction management in PeLEDs based on theoretical and experimental analysis. The abundant strategies, including surface passivation, ligand engineering, cation/anion mixing, and utilizing the efficient energy funneling of 2D layered structure perovskites, have advanced the internal quantum efficiency more than 90%. However, the EQE beyond the 20% limit and operational stability, owing to a large portion of photon trapping within the thin layer of PeLEDs stack, remain and impede further advancements. Undoubtedly, the remarkable properties of perovskites, including the high PLQY, narrow emission peak, small Stokes shift, and facile synthesis at a lower temperature, are an encouragement to develop high-performance PeLEDs, which is an inevitable trend of practical applications. Nevertheless, the low operational stability, isotopically oriented emitters, refractive indices discrepancy, and high non-radiative losses owing to poor film coverage and thickness are the few detrimental factors limiting the out-coupling efficiency. Based on existing literature, we have reviewed the outcoupling management in pattern-nanostructures photonics (quantum wires), vertically oriented quasi-2D perovskites, high-index grading, and anisotropically oriented nanoplatelet emitters (high horizontal dipole ratios of more than 76%). Finally, we have postulated a few strategies for outcoupling efficiency management by examining the photon-recycling process and thickness management in ITO and EML.

Conflicts of interest

There are no conflicts to declare.

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